RENESAS

RAA212831

4.5V to 72V Input, 0.5A Buck Regulator with Two Linear Regulator Outputs

The RAA212831 is a triple output regulator combining a 4.5V to 72V input, 0.5A buck regulator with two LDO outputs. The buck regulator has a fixed switching frequency of 350kHz in Continuous Conduction mode (CCM) and operates in pulse skipping mode at lighter loads when it enters Discontinuous Conduction mode (DCM). The two LDOs operate from a 12V (or lower) input voltage. The LDOs are rated at 100mA and 50mA of output current. The buck regulator output can be set from 1.25V to V_{IN} ×Dmax. The LDOs can support an input voltage range of 6V to 12V and the output voltages are fixed at 3.3V and 5V. The IC is designed to provide a compact, highly integrated power management solution. Its integrated buck regulator and LDO outputs minimize system component count.

The buck converter uses peak current mode control, providing 500mA current for load and downstream LDO regulators, while the LDOs provide 5V and 3.3V regulated outputs for the system. The current-mode buck converter provides a fast transient response and cycle-by-cycle switching current limit. All output voltages are fixed internally with few external components required.

At light load or no-load operation on the buck regulator output, the RAA212831 operates in a pulse skipping mode in DCM. When the output load is increased, and the buck regulator enters CCM, the controller operates at 350kHz.

The RAA212831 offers comprehensive protection including UVLO, high-side overcurrent, output undervoltage, and over-temperature protection.

The device is available in SOIC8-E package.

Features

- Buck Converter:
 - 4.5V to 72V input voltage
 - Adjustable output voltage from 1.25V to V_{IN} ×Dmax
 - 500mA output load capability
 - 0.6Ω high-side MOSEFT r_{DS(ON)}
 - Fixed switching frequency 350kHz in CCM operation
 - Pulse skipping mode in DCM operation
 - 6V standby function by external components
 - High-side OCP, UVP, UVLO, OTP fault protection
- 5V LDO Regulator:
 - 6V to 12V input voltage
 - Fixed output voltage 5V
 - 100mA output load capability
 - Current limit foldback function
- 3.3V LDO Regulator:
 - 4.5V to 12V input voltage
 - Fixed output voltage 3.3V
 - 50mA output load capability
 - Current limit foldback function
- SOIC8-E package

Applications

- Electric-bike power management
- Motor driver control board power supply





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1. Overview

1.1 Typical Applications



Figure 2. Typical Application Diagram without External Standby Function



Figure 3. Typical Application Diagram with External Standby Function



1.2 Block Diagram



Figure 4. Functional Block Diagram



2. Pin Information

2.1 Pin Assignments



2.2 Pin Descriptions

Pin Number	Pin Name	Description	
1	VIN	Input voltage for the IC and buck converter	
2	GND	Ground	
3	FB	Feedback pin. 1.25V ±3% over temperature range	
4	LDO_3V3	LDO output voltage, fixed 3.3V	
5	LDO_5V	LDO output voltage, fixed 5V	
6	LDO_VIN	Input voltage for the LDOs	
7	BST	Bootstrap supply pin	
8	SW	Switch node output	



3. Specifications

3.1 Absolute Maximum Ratings

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.

Parameter	Minimum	Maximum	Unit
VIN	-0.3	76	V
SW	-0.7	VIN + 0.3	V
BST		SW + 4	V
BST to SW	-0.3	4	V
LDO_VIN	-0.3	15	V
LDO_5V	-0.3	LDO_VIN + 0.3 or 6	V
LDO_3V3	-0.3	LDO_VIN + 0.3 or 4.3	V
All other pins	-0.3	4	V

3.2 ESD Ratings

ESD Model/Test	Rating	Unit
Human Body Model (Tested per JS-001-2017)	2	kV
Charged Device Model (Tested per JS-002-2018)	750	V
Latch-Up (Tested per JESD78E; Class 2, Level A)	100	mA

3.3 Recommended Operating Conditions

Parameter	Minimum	Maximum	Units
Supply Voltage, V _{IN}	4.5	72	V
Supply Voltage, LDO_VIN for both LDOs active	6	12	V
Supply Voltage, LDO_VIN for LDO_3V3 only	4.5	12	V
Output Voltage, V _{OUT}	1.25	V _{IN} × Dmax	V
Output Current, I _{OUT}	0	0.5	A
Output Current, I _{LDO_5V}	0	0.1	A
Output Current, I _{LDO_3V3}	0	0.05	A



3.4 Thermal Specifications

Thermal Resistance (Typical)	θ _{JA} (°C/W) ^[1]	θ _{JC} (°C/W) ^[2]
SOIC8-E Package	48	7

 θ_{JA} is measured in free air with the component mounted on a high-effective thermal conductivity test board with direct attach features. See TB379.

2. For θ_{JC} , the case temperature location is the center of the exposed metal pad on the package underside.

Parameter	Minimum	Maximum	Unit
Maximum Junction Temperature	-40	+150	°C
Maximum Storage Temperature Range	-65	+150	°C
Ambient Temperature Range	-40	+125	°C
Pb-Free Reflow Profile		See TB493	

3.5 Electrical Specifications

 V_{IN} = 24V, V_{OUT} = 12V, unless otherwise noted. Typical values are at T_A = +25°C. Boldface limits apply across the ambient temperature range, -40°C to +125°C.

Parameter	Symbol	Test Conditions	Minimum ^[1]	Typical	Maximum ^[1]	Unit
VIN Voltage Range	V _{IN}		4.5		72	V
VOUT Voltage Range	V _{OUT}	Determined by Minimum off-time	1.25		Dmax × V _{IN}	V
VOUT Voltage Range when using output as LDO_VIN	V _{OUT}	Determined by Minimum off-time	6		12	V
Quiescent Current	Ι _Q	V _{FB} = 1.35V, no switching, included LDOs operation	240	325	400	μA
VIN Undervoltage Lockout	V _{UVLO_VIN}	V _{IN} Rising	4	4.25	4.45	V
VIN UVLO Hysteresis	V _{HYS_VIN-UVLO}	Falling		250		mV
Switching Frequency Range	FS	V _{FB} = 1.25V	318	350	389	kHz
Foldback Frequency	FS	V _{FB} = 0V		90		kHz
Feedback Voltage	V	V _{IN} = 12V, 25°C	1.23	1.25	1.27	V
Reference	V _{FB}	V _{IN} = 12V	1.21	1.25	1.29	V
Peak Current Limit		Duty Cycle = 90%, 25°C	0.7	0.82	0.97	А
Min Off-Time		25°C, Boot voltage need to work for smaller minimum off-time		260		ns
Min On-Time		Need to Regulate 350kHz, 72V _{IN} to $3.3V_{OUT}$		92	105	ns
High-Side FET $r_{DS(ON)}$				600		mΩ
UVP		Fault threshold, V _{FB} falling, Soft start completed		30		%
Internal Soft-Start Time				1.9		ms
Hiccup Timer				23		ms



V_{IN} = 24V, V_{OUT} = 12V, unless otherwise noted. Typical values are at T_A = +25°C. Boldface limits apply across the ambient	
temperature range, -40°C to +125°C.	

Parameter	Symbol	Test Conditions	Minimum ^[1]	Typical	Maximum ^[1]	Unit
Thermal Shutdown	ОТ			155		°C
Thermal hysteresis				20		°C
LDO_3V3				1	I	
LDO_VIN Voltage Range	LDO_VIN		4.5		12	V
LDO_3.3V Voltage Range	LDO_3V3	IOUT = 1mA to 50mA	3.17	3.3	3.43	V
LDO Supply Current		LDO_VIN ≥4.5V, IOUT = 0A		40	70	μA
Output Current			50			mA
Current Limit		LDO_3V3 = 3.3V		75		mA
Current Limit Foldback		LDO_3V3 =0V		25		mA
		I _{OUT} = 50mA, C _{OUT} = 4.7μF, FREQ = 100Hz		72		dB
PSRR		I_{OUT} = 50mA, C _{OUT} = 4.7µF, FREQ = 10kHz		82		dB
		I _{OUT} = 50mA, C _{OUT} = 4.7μF, FREQ = 100kHz		66		dB
Noise		I _{OUT} = 50mA, C _{OUT} = 4.7μF, BW = 10Hz - 100kHz		466		μVrms
LDO_5V					1	1
LDO_VIN Voltage Range	LDO_VIN		6		12	V
LDO_5V Voltage Range	LDO_5V	I _{OUT} = 1mA to 100mA	4.75	5	5.25	V
LDO Supply Current		LDO_VIN ≥6V, I _{OUT} = 0A		40	70	μA
Output Current			100			mA
Current Limit		LDO_5V = 5V		150		mA
Current Limit Foldback		LDO_5V =0V		50		mA
		I _{OUT} = 100mA, C _{OUT} = 4.7μF, FREQ = 100Hz		56		dB
PSRR		I_{OUT} = 100mA, C _{OUT} = 4.7µF, FREQ = 10kHz		69		dB
		I_{OUT} = 100mA, C _{OUT} = 4.7µF, FREQ = 100kHz		76		dB
Noise		I _{OUT} = 100mA, C _{OUT} = 4.7μF, BW = 10Hz - 100kHz		711		μVrms

1. Compliance to datasheet limits is assured by one or more methods: production test, characterization, and/or design.

4. **Typical Performance Graphs**

 V_{IN} = 56V, V_{OUT} = 6V, T_A = +25°C, unless otherwise noted.



Figure 5. Load Regulation





2µs/Div

Figure 7. Buck Output Ripple at Full Load



Figure 8. Buck Output Ripple at No Load





Figure 10. Power-On at Full Load with LDO Channels









200µs/Div

Figure 11. Load Transient between 0.25A to 0.5A

Figure 12. With External Standby Function at Full Load







2µs/Div

Figure 15. Buck Output Ripple at Full Load

100 90 80 Efficiency (%) 70 60 VIN = 24V VIN = 16V 50 VIN = 36V VIN = 48V VIN = 64V VIN = 56V40 VIN = 72V 30 0.1 0 0.2 0.3 0.4 0.5 Output Load (A)





400µs/Div

Figure 16. Buck Output Ripple at No Load

 V_{IN} = 56V, V_{OUT} = 12V, T_A = +25°C, unless otherwise noted. (Cont.)





10ms/Div

Figure 17. Power-On at Full Load





Figure 19. Load Transient between 0.25A to 0.5A



VOUT = VINLDO = 6V, VLDO5V = 5V, VLDO3V3 = 3.3V, TA = +25°C, unless otherwise noted.





VOUT = VINLDO = 6V, VLDO5V = 5V, VLDO3V3 = 3.3V, TA = +25°C, unless otherwise noted. (Cont.)



200µs/Div





Figure 24. VLDO5V Load Transient between 0A to 0.1A







Figure 27. VLDO3V3 PSRR at Full Load



Figure 26. VLDO5V OCP Fault with Current Foldback



Figure 28. VLDO5V PSRR at Full Load

VOUT = VINLDO = 6V, VLDO5V = 5V, VLDO3V3 = 3.3V, TA = +25°C, unless otherwise noted. (Cont.)



V_{OUT} = VINLDO = 12V, C_{OUT} = 4.7μF,0.1μF

5. Functional Description

 V_{OUT} = VINLDO = 6V, C_{OUT} = 4.7 μ F,0.1 μ F

The following operating description of the RAA212831 refers to the functional block diagram shown in Figure 4 and the application diagram shown in Figure 1. The RAA212831 generates a regulated output voltage by switching the internal NMOS control switch at constant frequency and variable duty cycle. The external inductor, freewheel diode, and output capacitor filter the switching waveform and create the DC output voltage.

A switching cycle begins at the falling edge of the reset pulse generated by the internal oscillator. When this pulse goes low, the output control logic turns on the internal NMOS control switch. During this on-time, the SW pin voltage (V_{SW}) swings up to approximately V_{IN} , and the inductor current (I_L) increases with a linear slope. I_L is measured by the current sense amplifier that generates an output proportional to the switch current. The sense signal is summed with the corrective ramp of the regulator and is compared to the output of the error amplifier, which is proportional to the difference between the feedback voltage and VREF.

When the PWM comparator output goes high, the output switch turns off until the next switching cycle begins. During the switch off-time, the inductor current discharges through the Schottky freewheel diode, forcing the SW pin to swing below ground by the forward voltage (VD) of the Schottky freewheel diode. The regulator loop adjusts the duty cycle (D) to maintain a constant output voltage.

To increase the light load efficiency of the buck converter, the chip enters pulse skipping mode and reduces the switching frequency. This occurs when the reduction in load current causes the buck regulator to transition from CCM to DCM. If the output load on buck converter is increased, CCM operation resumes and the PWM switching frequency is fixed at 350kHz.

The buck output voltage should be connected to the LDO_VIN pin to provide bias for LDO_3V3 and LDO_5V. The LDO_VIN pin is also used as an undervoltage monitor for the buck output voltage.

5.1 Soft-Start for Buck

Soft-start forces the regulator output to ramp up in a controlled fashion, which helps reduce input inrush current into the buck output capacitors. During the soft-start period for the buck converter, the reference voltage of the error amplifier ramps from 0V to its nominal value of 1.25V in approximately 1.8ms.

5.2 Soft-Start for LDOs

This function forces the LDOs output voltages to increase at a controlled rate during start-up. During soft-start for the two LDOs, the reference voltage of the error amplifier ramps from 0V to its nominal value of 1.25V in approximately 2.550ms.

5.3 Undervoltage Lockout

Undervoltage lockout (UVLO) prevents the RAA212831 from operating until the input voltage exceeds 4.25V (typical). The UVLO threshold has approximately 250mV of hysteresis; therefore, the device operates until V_{IN} drops below 4V (typical). Hysteresis prevents the part from turning off during power up if V_{IN} is non-monotonic.

5.4 Current Limit for Buck

The RAA212831 uses cycle-by-cycle current limiting to protect the output switch. During each switching cycle, a current limit comparator detects if the output switch current exceeds 0.82A (typical) and turns off the switch until the next switching cycle begins.

To reduce the current limit at low duty cycle, the RAA212831 has a frequency foldback function that depends on the feedback voltage to control the switching frequency. For example, if the feedback voltage is 0V, the switching frequency is 90kHz (typical).

5.5 Current Limit for LDOs

The RAA212831 has internal current limiting functionality to protect the regulator during fault conditions. The RAA212831 has two levels of current limit protection. During an overcurrent event, when the output voltage has fallen to less than 50% of the nominal setpoint voltage, the chip enters the current limit foldback operation with a lower current limit value. If the short or overload is removed from the LDO output, the output returns to normal voltage regulation mode.

5.6 Output Undervoltage Protection for Buck

The undervoltage comparator compares the LDO_VIN pin voltage to a reference level that is 30% of the buck output voltage. Assuming the buck output voltage is set to 12V, and this voltage drops below 30% of the nominal setpoint (3.6V), and the chip is also operating in current limit protection mode, the controller turns off the internal high-side FET and engages hiccup mode operation. When this fault is removed and V_{OUT} is above 30% of the nominal setpoint (3.6V), the buck output rail returns to normal voltage regulation mode.

5.7 Thermal Shutdown

Thermal shutdown limits total power dissipation by turning off the output switch when the IC junction temperature exceeds 155°C (typical). After thermal shutdown occurs, the output switch does not turn on until the junction temperature drops to approximately 135°C (typical).

6. Applications Information

6.1 Input Capacitor Selection

The input capacitor is used in Buck converter to maintain the input voltage by suppressing the voltage ripple induced by discontinuous switching current. The required RMS current rating $I_{IN(RMS)}$ of the input capacitor is calculated using Equation 1.

(EQ. 1)
$$I_{IN(RMS)} = I_{OUT(MAX)} \times \sqrt{D \times (1-D)}$$

where $I_{OUT(MAX)}$ is the maximum average load current and D is the duty ratio. When D equals 0.5, $I_{IN(RMS)}$ has the maximum value which is $I_{OUT(MAX)}/2$.

The voltage rating of the input capacitor should be higher than the maximum input voltage. The required capacitance C_{IN} of the input capacitor to ensure the expected peak-to-peak input voltage ripple ΔV_{IN} is calculated using Equation 2:

(EQ. 2) $C_{IN} = I_{OUT(MAX)} \times \frac{D \times (1-D)}{f_{SW} \times \Delta V_{IN}}$

where f_{sw} is the switching frequency. The required capacitance also has the maximum value when D equals 0.5. It is suggested to use ceramic capacitors as input capacitor, which has low ESR and low ESL. When selecting the ceramic capacitor, it should be considered that the effective capacitance reduces with DC bias voltage across it. Also, Renesas recommends using X7R ceramic capacitors because of their small temperature coefficient.

If the part is connected to the power source through a high impedance path, Renesas recommends adding an electrolytic capacitor in addition to the ceramic capacitor to damp the input voltage oscillation.

6.2 Output Voltage for Buck

The output voltage for the buck regulator output can be programmed down to 1.25V with a resistor divider from VOUT to the FB pin to GND based on Equation 3. The recommended R_{FB2} (see Figure 1) resistance is 20k Ω . See Table 1 for R_{FB1} and R_{FB2} values for typical V_{OUT} applications.

(EQ. 3)
$$R_{FB1} = R_{FB2} \times \frac{V_{OUT} - 1.25}{1.25}$$

6.3 Output Voltage for LDOs

The output voltage for the LDO_3V3 rail is fixed at 3.3V. The output voltage for the LDO_5V rail is fixed at 5V. Renesas recommends using the buck output voltage to supply LDO_VIN between 6V and 12V for both LDOs to be operational. If only the LDO_3V3 rail is required, LDO_VIN can be between 4.5V and 12V, with LDO_5V failing to regulate.

6.4 Inductor Selection

The inductor value determines the ripple current of the buck converter. A reasonable starting point for choosing the ripple current, ΔI_L , is 30% to 60% of total load current. The inductor value is then calculated using Equation 4:

(EQ. 4)
$$L = \frac{V_{IN} - V_{OUT}}{f_{SW} \times \Delta I} \times \frac{V_{OUT}}{V_{IN}}$$

As an example, using V_{IN} = 56V, V_{OUT} = 12V, f_{SW} is fixed at 350kHz, I_{OUT} = 500mA, and $\Delta I/I_{OUT}$ = 45%, the inductance is calculated as follows:

(EQ. 5)
$$L = \frac{56V - 12V}{350 \text{kHz} \times 0.45 \times 500 \text{mA}} \times \frac{12V}{56V} = 120 \mu \text{H}$$

Increasing the inductance value reduces the ripple current and the ripple voltage. However, the larger inductance value may reduce the response time of the converter to a load transient. **Note:** The inductor current rating should not be exceeded in overcurrent conditions to avoid saturation.

For lowest loss and smallest output voltage ripple, chose an inductor with the smallest possible DC resistance, provided its mechanical dimensions meet application requirements. For typical RAA212831 applications, inductor values generally lie in the 70μ H to 120μ H range. See Table 1 when selecting the inductor value for typical values of V_{OUT}.

6.5 Output Capacitor Selection (Buck)

The output capacitor determines both steady state performance and transient performance of the Buck converter. Factors such as output voltage ripple, output voltage variation during transients, and control loop stability should be considered when selecting the output capacitor. X7R dielectric ceramic capacitors are recommended. **Note:** When selecting the ceramic capacitor, the actual capacitance may be considerably lower than the advertised value. Consult the datasheet of the manufacturer to determine the actual in-application capacitance. Most manufacturers publish capacitance vs DC bias so that this effect can be easily accommodated. The effects of AC voltage are not frequently published; however, an assumption of ~20% further reduction generally suffices. The result of these considerations may mean an effective capacitance 50% lower than nominal, and this value should be used in all design calculations. However, ceramic capacitors are a good choice in many applications because of their reliability and extremely low ESR.

For the ceramic capacitor, its capacitance is dominating the voltage ripple. Therefore, the required capacitance $C_{OUT(RIPPLE)}$ for the expected peak-to-peak output voltage ripple $\Delta V_{OUT(RIPPLE)}$ is calculated using Equation 6:

(EQ. 6)
$$C_{OUT(RIPPLE)} = \frac{\Delta I_L}{8 \times f_{SW} \times \Delta V_{OUT(RIPPLE)}}$$

where ΔI_L is the peak-to-peak inductor ripple current, f_{sw} is fixed at 350kHz, and $\Delta V_{OUT(RIPPLE)}$ is required ripple voltage.

To meet the output voltage variation requirements during load transient with step up and step down, the required capacitance $C_{OUT(STEPUP)}$ is calculated using Equation 7 and $C_{OUT(STEPDOWN)}$ is calculated using Equation 8:

(EQ. 7)
$$C_{OUT(STEPUP)} = \frac{L \times \left(I_{STEP} + \frac{\Delta I_L}{2}\right)^2}{2 \times (V_{IN} - V_{OUT}) \times \Delta V_{OUT}}$$

(EQ. 8)
$$C_{OUT(RIPPLE)} = \frac{L \times \left(I_{STEP} + \frac{\Delta I_L}{2}\right)^2}{2 \times V_{OUT} \times \Delta V_{OUT}}$$

where L is the inductor value, I_{STEP} is the transient load step, ΔI_L is the peak-to-peak inductor ripple current, and ΔV_{OUT} is the expected voltage variation during the transient.

For convenience, Table 1 can be referenced when selecting output capacitors for typical V_{OUT} applications.

6.6 Output Capacitor Selection (LDOs)

For a compact and high performance solution, the RAA212831 has two integrated LDOs that are designed specifically to work with low ESR X7R ceramic output capacitors. Using an X7R ceramic capacitor with capacitance of at least 4.7 μ F and ESR larger than 1m Ω on the RAA212831 output ensures stability. Nevertheless, the RAA212831 still works well with other types of output capacitors that have higher ESR values. Place the output capacitor no more than 0.5 inch from the output pin of the RAA212831.

6.7 Diode Selection

The RAA212831 requires a freewheeling diode for inductor current to flow when the internal high-side MOSFET is turned off. Select a diode with reverse voltage rating at least 20% higher than the maximum input voltage. The continuous current rating of the diode should be greater than the highest output current. For better efficiency, select a diode with low forward voltage drop and fast reverse recovery time. Schottky diodes are recommended for this application

6.8 Boot Capacitor Selection

A capacitor is needed between BST pin and SW pin to provide gate voltage for the high-side internal MOSFET. Renesas recommends using a 16V X7R 0.1µF ceramic capacitor as the bootstrap capacitor for most applications.

V _{OUT} (V)	R _{FB1} (kΩ)	R _{FB2} (kΩ)	L (µH)	C _{OUT} for Buck	C _{OUT} for LDOs
6	76	20	70	2×10µF/1206/35V/X7R	4.7µF/0805/10V/X7R
8	108	20	90	2×10µF/1206/35V/X7R	4.7µF/0805/10V/X7R
10	140	20	100	2×10µF/1206/35V/X7R	4.7µF/0805/10V/X7R
12	172	20	120	2×10µF/1206/35V/X7R	4.7µF/0805/10V/X7R

 Table 1. Recommended Components Selection for Typical Applications

7. Layout Guidelines

- Place the input ceramic capacitor(s) as close as possible to the IC VIN PIN and the diode. Keep the power loop (input ceramic capacitor, IC VIN pin, and diode) as small as possible to minimize VSW node voltage ringing induced by trace parasitic inductance. This also results in better EMI performance.
- If an aluminum electrolytic capacitor is used, place it as close as possible to the IC VIN pin.
- Keep the VSW node copper area small for less parasitic capacitance but large enough to handle the load current.
- Place the output capacitor(s) close to the inductor and freewheel diode.
- Connect the power ground (CIN, diode, and COUT ground) to the analog ground plane, which connects to the GND pin. Use a single point connection.
- Route the buck output etches close to the LDO_VIN pin and away from the VSW node.



8. Package Outline Drawing

For the most recent package outline drawing, see M8.15H.

M8.15H

8 Lead Narrow Body Small Outline Exposed Pad Plastic Package (EPSOIC)

Rev 1, 1/20





9. Ordering Information

Part Number ^{[1][2]}	Part Marking	Package Description (RoHS Compliant)	Pkg. Dwg. #	Carrier Type ^[3]	Temp Range
RAA2128314GSP#HA0	RAA 212831	8 Ld EPSOIC	M8.15H	Reel, 2.5k	-40 to +125°C
RTKA212831DR0000BU	Demonstration Board				

 These Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate - e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J-STD-020.

2. For the Moisture Sensitivity Level (MSL), see the RAA212831 product page. For more information about MSL, see TB363.

3. See TB347 for details about reel specifications.

Part Number	Buck V _{OUT}	Pin Difference
RAA212831	1.25V to V _{IN} ×Dmax by FB resistor settings	FB Pin
RAA212832	6V or 12V by STBY pin settings	STBY Pin

Table 2. Key Differences Between Family of Parts

10. Revision History

Revision	Date	Description
1.02	Mar 2, 2023	Updated the VOUT Voltage Range maximum on page 1 and Table 2.
1.01	Apr 19, 2022	 Updated 3.3V LDO input voltage bullet on page 1. Added Supply Voltage, LDO_VIN for LDO_3V3 only operating condition. Updated Output Voltage, VOUT operating condition maximum value from 24V to V_{IN} × Dmax. Updated the following specifications in the Electrical Specifications section: Changed VOUT Voltage Range maximum from 24V to V_{IN} × Dmax. Added VOUT Voltage Range when using output as LDO_VIN specification. Changed Switching Frequency Range minimum value from 317.8kHz to 318kHz and the maximum spec from 388.5kHz to 389kHz. Changed Feedback Voltage Reference minimum values from 1.213V to 1.23V and from 1.213V to 1.21V and the maximum values from 1.269V to 1.27V and from 1.288V to 1.29V. Added Min On-Time maximum specification value and changed typical from 96ns to 92ns. Changed LDO_VIN Voltage Range minimum spec from 6V to 4.5V. Changed LDO_3.3V Voltage Range minimum spec from 3.168V to 3.17V and the maximum spec from 3.432V to 3.43V. Added Output Current and Noise specifications for both LDO_3V3 and LDO_5V. Updated LDO_5V Voltage Range changed minimum value from 58dB to 72dB, from 40dB to 82dB, and from 28dB to 66dB. Updated LDO_5V Voltage Range changed minimum value from 58dB to 56dB, from 40dB to 69dB, and from 28dB to 76dB. Updated Figures 27 and 28. Added Figures 29 and 30. Updated Ordering information table.
1.00	Sep 24, 2021	Initial release.

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